## NSN 5962-01-135-2102

Memory Microcircuit - Page 1 of 2



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-	Length:
1.310 i	nches
Body \	Width:
0.600 i	nches
Body I	Height:
0.052 i	nches
Maxim	um Power Dissipation Rating:
400.0 r	nilliwatts
Operat	ting Tempurature Range:
+0.0/+7	75.0 degrees celsius
Storag	e Tempurature Range:
-65.0/+	150.0 degrees celsius
End A	pplication:
Trainin	g dev 08783
Featur	es Provided:
Herme	tically sealed and programmable and expandable and wire-or outputs and w/enable
Inclos	ure Material:
Ceram	ic and glass
Inclos	ure Configuration:
Dual-in	n-line
Outpu	t Logic Form:
Transis	stor-transistor logic
Input C	Circuit Pattern:
8 input	
Termir	nal Surface Treatment:
Solder	
Voltag	e Rating And Type Per Characteristic:
-1.5 vo	Its power source and 5.5 volts power source
Time F	Rating Per Chacteristic:
75.00 r	nanoseconds propagation delay time, low to high level output
Memo	ry Device Type:
Rom	
Memo	ry Capacity:
Unknov	wn
Termir	nal Type And Quantity:
24 prin	ted circuit
Shelf L	_ife:
N/a	
Unit O	f Measure:
Demili	tarization:
Ves - d	lemil/mli

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Memory Microcircuit - Page 2 of 2

**Fiig:** A458a0

